

Power Rectifier Diodes (T-Modules), 40 A to 110 A



D-55

FEATURES

- Electrically isolated base plate
- Types up to 1200 V_{RRM}
- 3500 V_{RMS} isolating voltage
- Simplified mechanical designs, rapid assembly
- High surge capability
- Large creepage distances
- UL E78996 approved 
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level



RoHS
COMPLIANT

PRODUCT SUMMARY

$I_{F(AV)}$	40 A to 110 A
Type	Modules - Diode, High Voltage

DESCRIPTION

These series of T-modules use standard recovery power rectifier diodes. The semiconductors are electrically isolated from the metal base, allowing common heatsink and compact assembly to be built.

Applications include power supplies, battery charges, welders, motor controls and general industrial current rectification.

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	T40HF	T70HF	T85HF	T110HF	UNITS
$I_{F(AV)}$		40	70	85	110	A
	T_C	85	85	85	85	°C
$I_{F(RMS)}$		63	110	134	173	A
I_{FSM}	50 Hz	570	1200	1700	2000	A
	60 Hz	600	1250	1800	2100	
I^2t	50 Hz	1630	7100	14 500	20 500	A ² s
	60 Hz	1500	6450	13 500	18 600	
$I^2\sqrt{t}$		16 300	70 700	148 700	204 300	A ² √s
V_{RRM}		100 to 1200				V
T_J		- 40 to 150				°C

T40HF..., T70HF..., T85HF..., T110HF... Series

Vishay Semiconductors

Power Rectifier Diodes
(T-Modules), 40 A to 110 A



ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 25 °C μA
T40HF... T70HF... T85HF... T110HF...	10	100	150	100
	20	200	300	
	40	400	500	
	60	600	700	
	80	800	900	
	100	1000	1100	
	120	1200	1300	

FORWARD CONDUCTION									
PARAMETER	SYMBOL	TEST CONDITIONS			T40HF	T70HF	T85HF	T110HF	UNITS
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave			40	70	85	110	A
					85	85	85	85	°C
Maximum RMS forward current	I _{F(RMS)}				63	110	134	173	A
Maximum peak, one-cycle forward, non-repetitive surge current	I _{FSM}	t = 10 ms	No voltage reapplied	Sinusoidal half wave, initial T _J = T _J maximum	570	1200	1700	2000	A
		t = 8.3 ms			600	1250	1800	2100	
		t = 10 ms	100 % V _{RRM} reapplied		480	1000	1450	1700	
		t = 8.3 ms			500	1050	1500	1780	
Maximum I ² t for fusing	I ² t	t = 10 ms	No voltage reapplied		1630	7100	14 500	20 500	A ² s
		t = 8.3 ms			1500	6450	13 500	18 600	
		t = 10 ms	100 % V _{RRM} reapplied		1150	5000	10 500	14 500	
		t = 8.3 ms			1050	4570	9600	13 200	
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reapplied			16 300	70 700	148 700	204 300	A ² √s
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % × π × I _{F(AV)} < I < π × I _{F(AV)}), T _J maximum			0.66	0.76	0.68	0.68	V
High level value of threshold voltage	V _{F(TO)2}	(I > π × I _{F(AV)}), T _J maximum			0.84	0.95	0.90	0.86	
Low level value of forward slope resistance	r _{f1}	(16.7 % × π × I _{F(AV)} < I < π × I _{F(AV)}), T _J maximum			4.3	2.4	1.76	1.56	mΩ
High level value of forward slope resistance	r _{f2}	(I > π × I _{F(AV)}), T _J maximum			3.1	1.7	1.08	1.12	
Maximum forward voltage drop	V _{FM}	I _{FM} = π × I _{F(AV)} , T _J = 25 °C, t _p = 400 μs square pulse Average power = V _{F(TO)} × I _{F(AV)} + r _f × (I _{F(RMS)}) ²			1.30	1.35	1.27	1.35	V



T40HF..., T70HF..., T85HF..., T110HF... Series

Power Rectifier Diodes
(T-Modules), 40 A to 110 A

Vishay Semiconductors

BLOCKING							
PARAMETER	SYMBOL	TEST CONDITIONS	T40HF	T70HF	T85HF	T110HF	UNITS
Maximum peak reverse leakage current	I_{RRM}	$T_J = 150\text{ }^{\circ}\text{C}$	15	15	20	20	mA
RMS isolation voltage	V_{ISOL}	50 Hz, circuit to base, all terminals shorted $T_J = 25\text{ }^{\circ}\text{C}$, $t = 1\text{ s}$	3500	3500	3500	3500	V

THERMAL AND MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES				UNITS
				T40HF	T70HF	T85HF	T110HF	
Maximum junction operating and storage temperature range	T _J , T _{Stg}			- 40 to 150				°C
Maximum thermal resistance, junction to case per junction	R _{thJC}	DC operation		1.36	0.69	0.62	0.47	K/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface smooth, flat and greased		0.2				
Mounting torque, to heatsink ± 10 % terminals		Non-lubricated threads	M3.5 mounting screws ⁽¹⁾	1.3 ± 10 %				Nm
			M5 screw terminals	3 ± 10 %				
Approximate weight		See dimensions - link at the end of datasheet			54			g
Case style					T-module (D-55)			

Note

⁽¹⁾ A mounting compound is recommended and the torque should be rechecked after a period of about 3 hours to allow for the spread of the compound

ΔR CONDUCTION PER JUNCTION											
DEVICES	SINUSOIDAL CONDUCTION AT T _J MAXIMUM					RECTANGULAR CONDUCTION AT T _J MAXIMUM					UNITS
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
T40HF...	0.12	0.14	0.18	0.27	0.46	0.09	0.15	0.20	0.28	0.46	K/W
T70HF...	0.09	0.11	0.14	0.20	0.35	0.07	0.11	0.15	0.21	0.35	
T85HF...	0.08	0.09	0.12	0.18	0.31	0.06	0.10	0.13	0.19	0.31	
T110HF...	0.05	0.07	0.09	0.14	0.23	0.05	0.08	0.10	0.15	0.24	

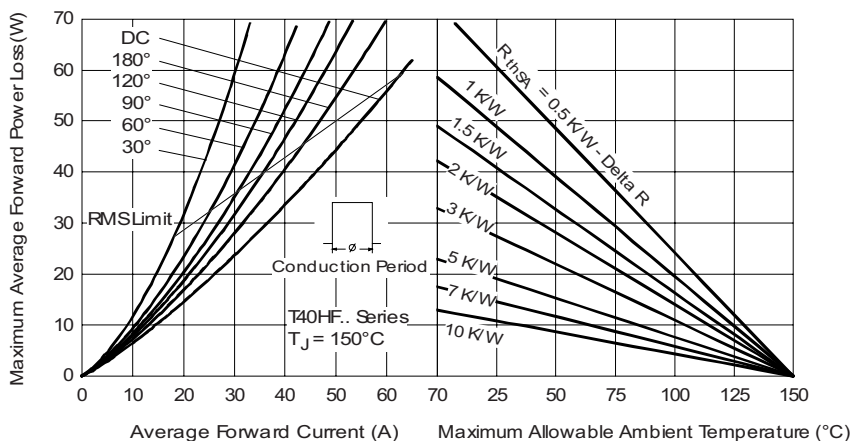
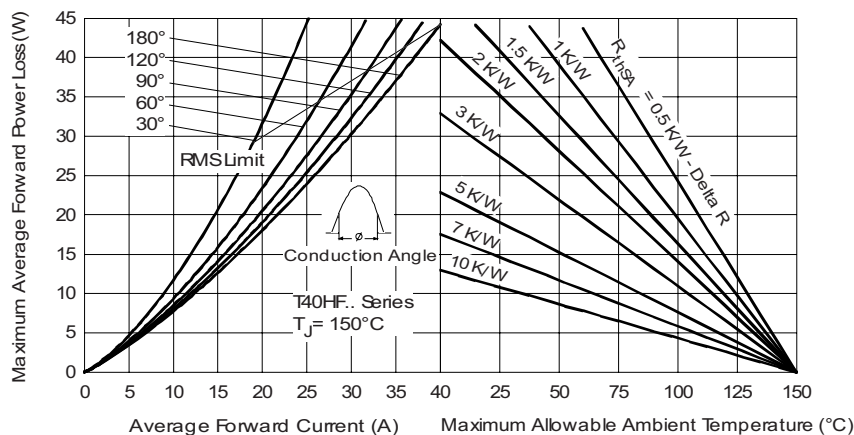
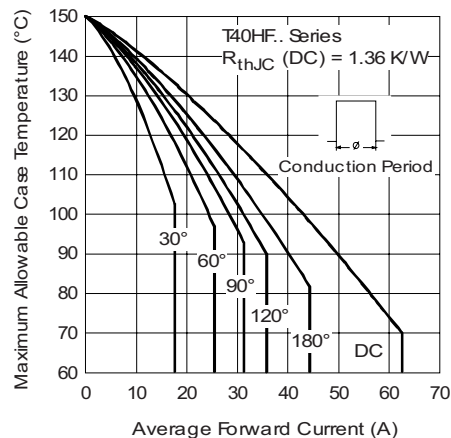
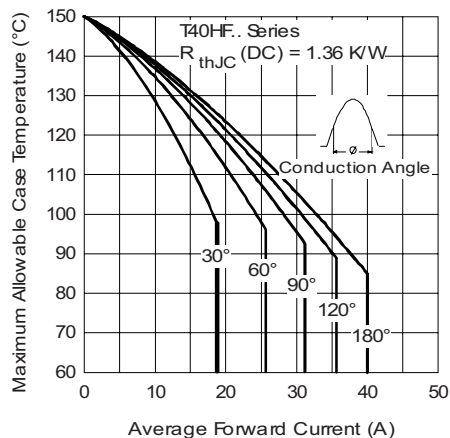
Note

- Table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

T40HF..., T70HF..., T85HF..., T110HF... Series

Vishay Semiconductors

Power Rectifier Diodes
(T-Modules), 40 A to 110 A





T40HF..., T70HF..., T85HF..., T110HF... Series

Power Rectifier Diodes
(T-Modules), 40 A to 110 A

Vishay Semiconductors

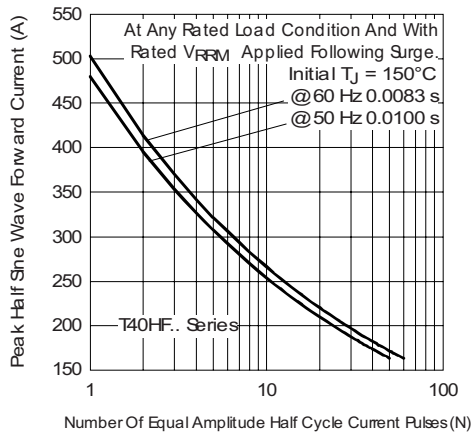


Fig. 5 - Maximum Non-Repetitive Surge Current

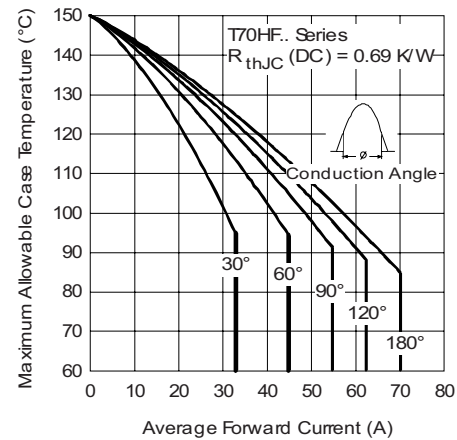


Fig. 7 - Current Ratings Characteristics

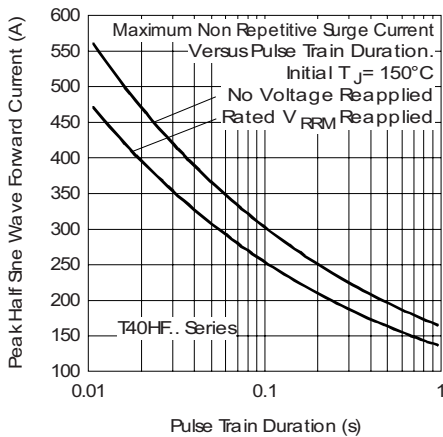


Fig. 6 - Maximum Non-Repetitive Surge Current

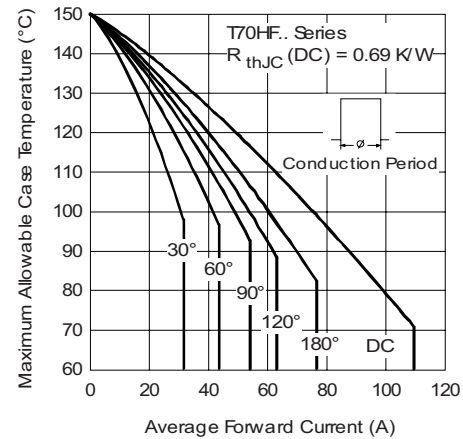


Fig. 8 - Current Ratings Characteristics

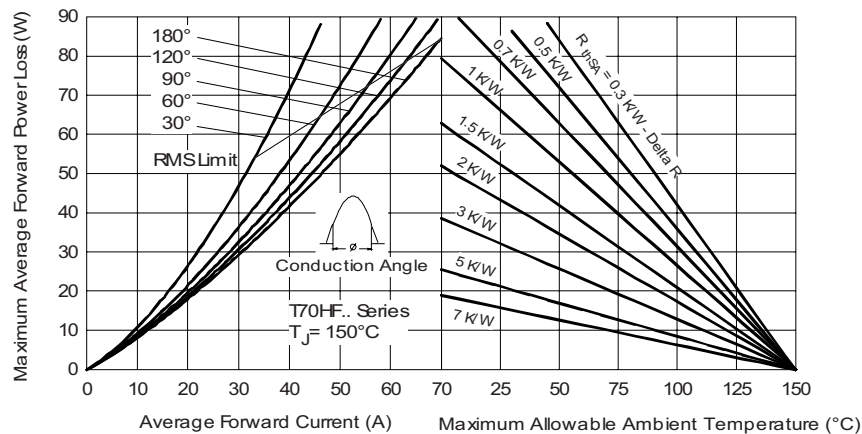


Fig. 9 - Forward Power Loss Characteristics

T40HF..., T70HF..., T85HF..., T110HF... Series

Vishay Semiconductors

Power Rectifier Diodes
(T-Modules), 40 A to 110 A

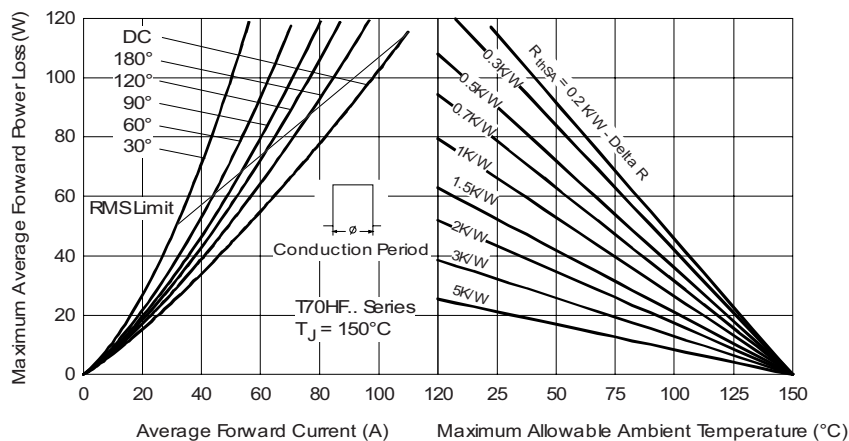


Fig. 10 - Forward Power Loss Characteristics

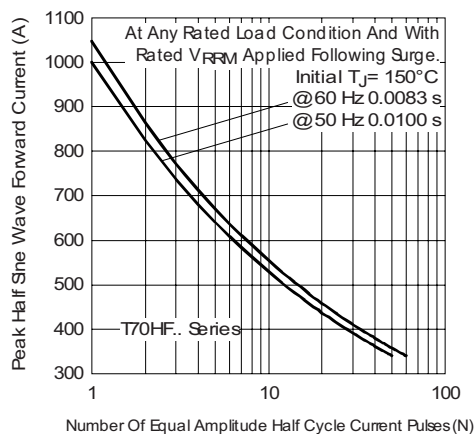


Fig. 11 - Maximum Non-Repetitive Surge Current

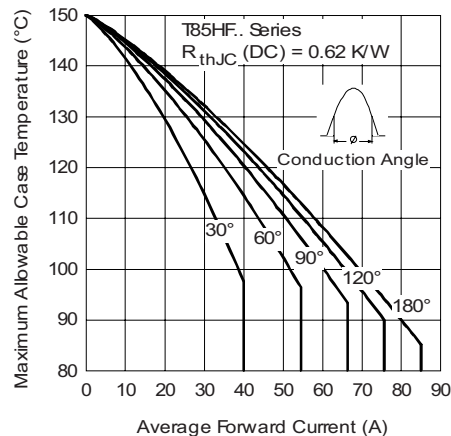


Fig. 13 - Current Ratings Characteristics

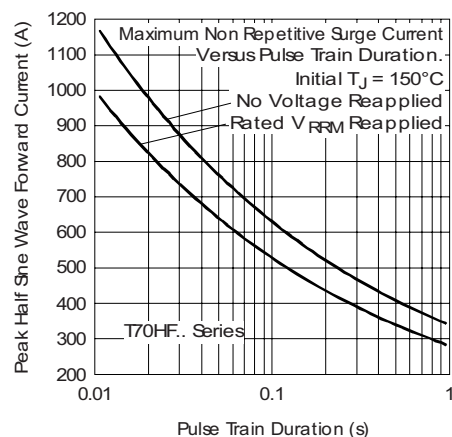


Fig. 12 - Maximum Non-Repetitive Surge Current

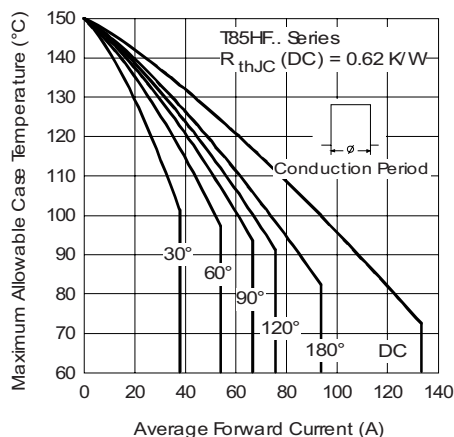


Fig. 14 - Current Ratings Characteristics



T40HF..., T70HF..., T85HF..., T110HF... Series

Power Rectifier Diodes
(T-Modules), 40 A to 110 A

Vishay Semiconductors

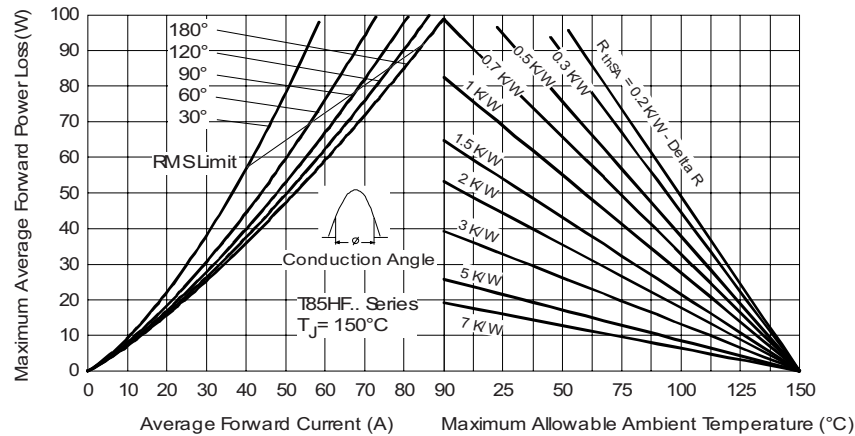


Fig. 15 - Forward Power Loss Characteristics

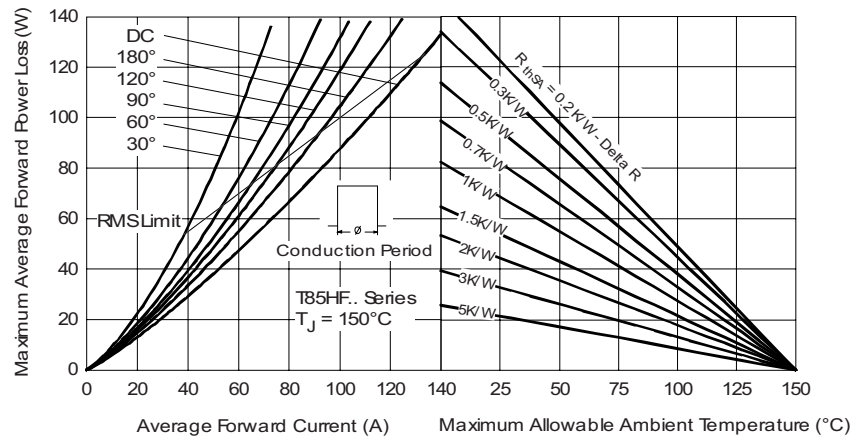


Fig. 16 - Forward Power Loss Characteristics

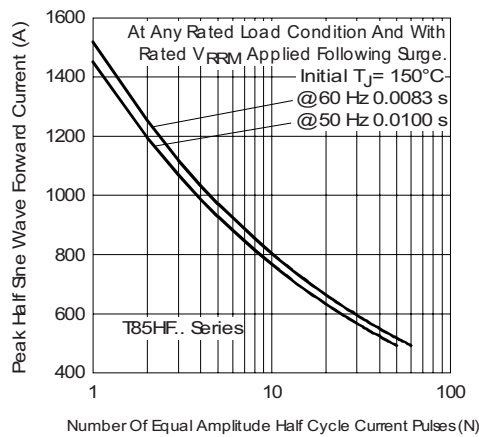


Fig. 17 - Maximum Non-Repetitive Surge Current

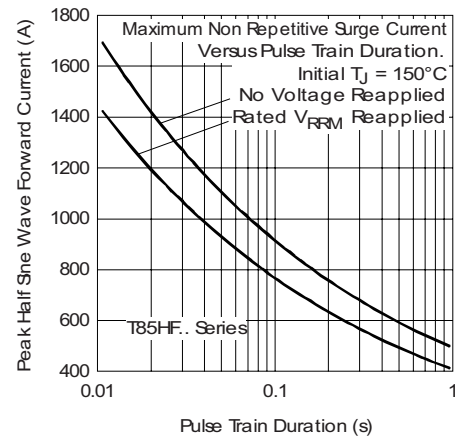
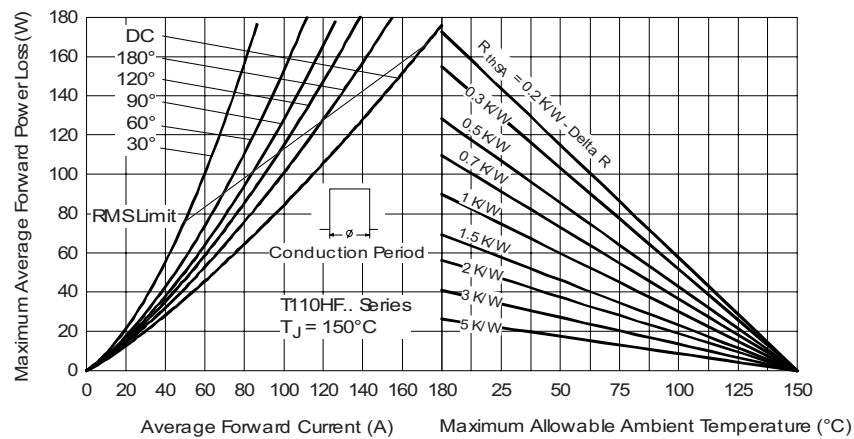
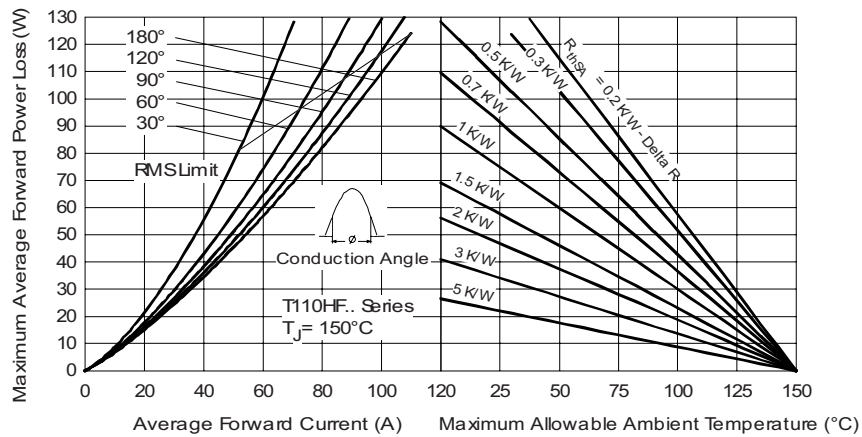
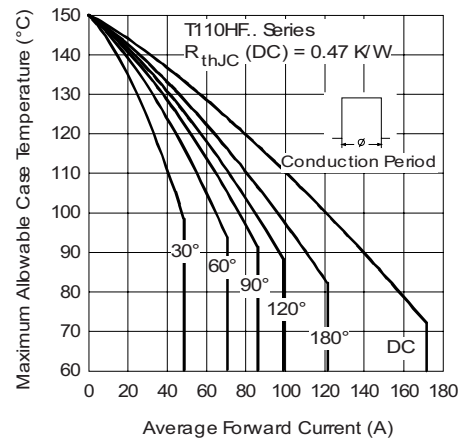
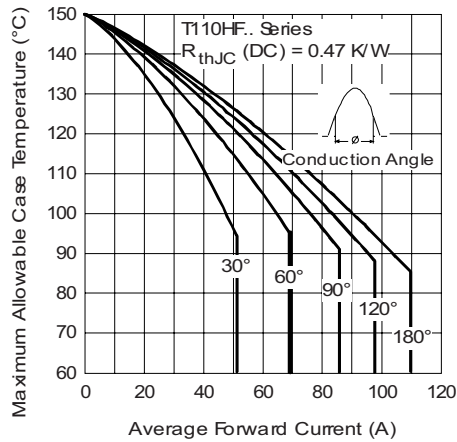


Fig. 18 - Maximum Non-Repetitive Surge Current

T40HF..., T70HF..., T85HF..., T110HF... Series

Vishay Semiconductors

Power Rectifier Diodes
(T-Modules), 40 A to 110 A





T40HF..., T70HF..., T85HF..., T110HF... Series

Power Rectifier Diodes
(T-Modules), 40 A to 110 A

Vishay Semiconductors

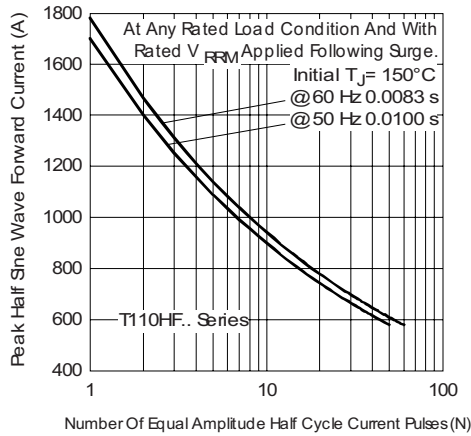


Fig. 23 - Maximum Non-Repetitive Surge Current

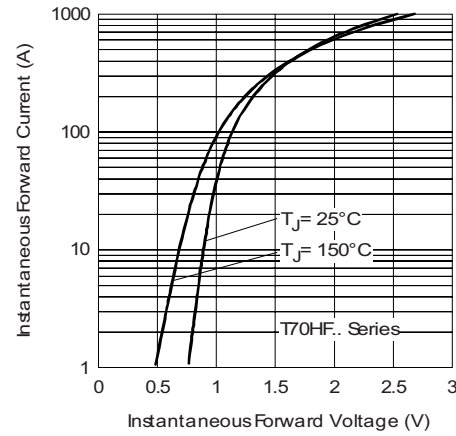


Fig. 26 - Forward Voltage Drop Characteristics

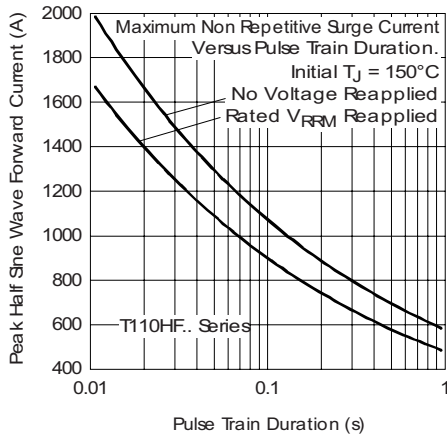


Fig. 24 - Maximum Non-Repetitive Surge Current

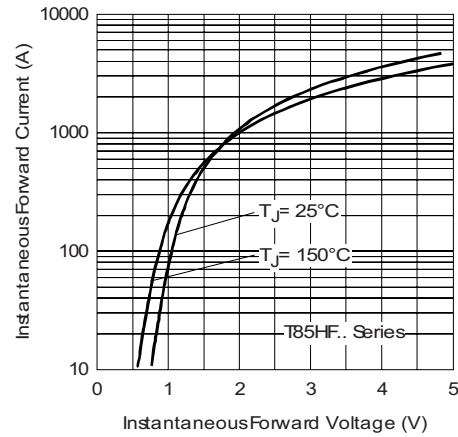


Fig. 27 - Forward Voltage Drop Characteristics

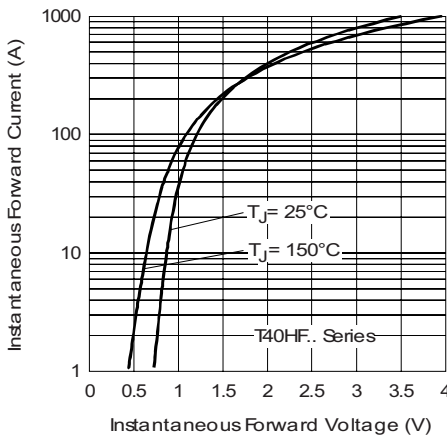


Fig. 25 - Forward Voltage Drop Characteristics

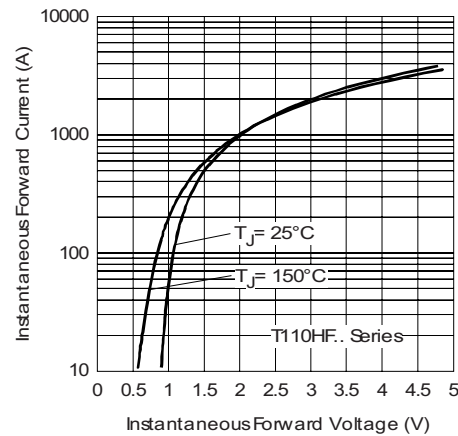


Fig. 28 - Forward Voltage Drop Characteristics

Vishay Semiconductors

Power Rectifier Diodes (T-Modules), 40 A to 110 A

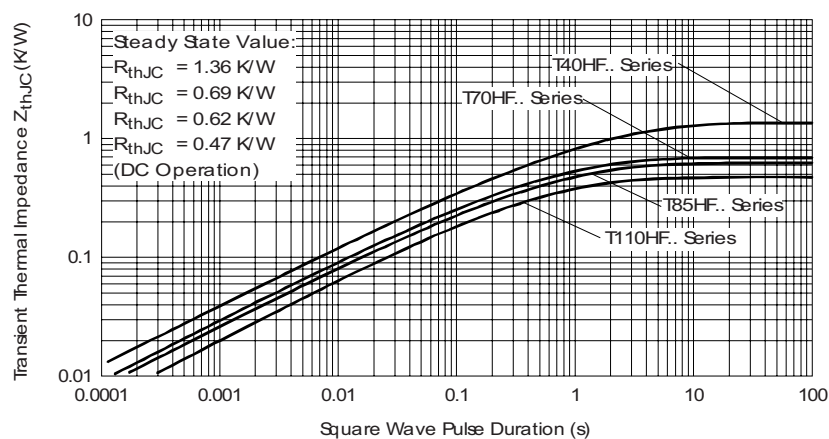


Fig. 29 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code

T	110	HF	120
----------	------------	-----------	------------

1 2 3 4

- 1** - Module type
- 2** - Current rating
- 3** - Circuit configuration (see Circuit Configuration table)
- 4** - Voltage code x 10 = V_{RRM}

Circuit Configuration		
Circuit Description	Circuit Configuration Code	Circuit Drawing
Single diode	HF	

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95313

DIMENSIONS in millimeters (inches)





Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.